

# Inverted Cylindrical Magnetron Sputtering of Optical Coatings

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# Introduction

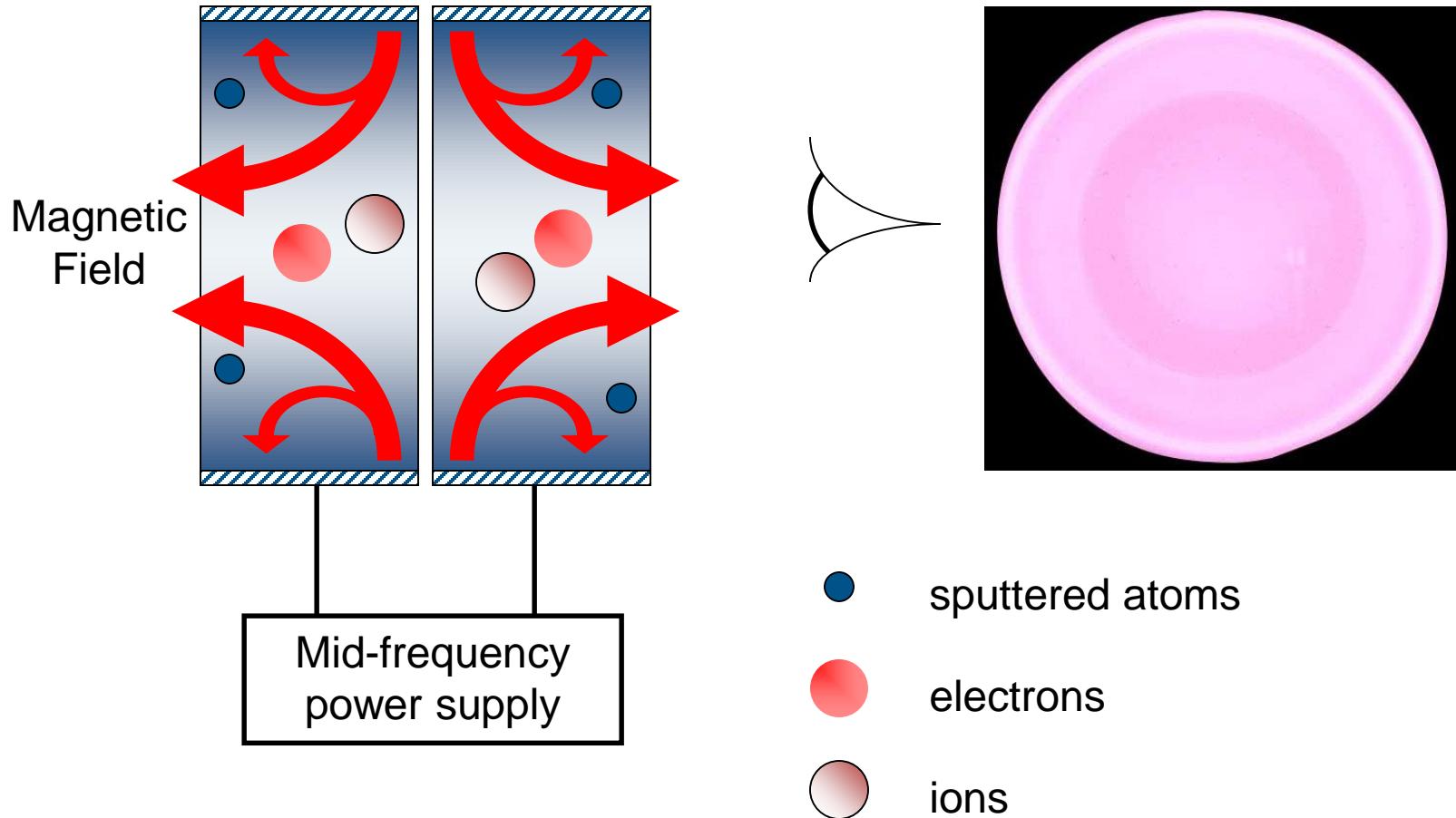
This work explores the use of off-axis cylindrical magnetron sputtering as a method for depositing optical coatings.

Earlier data showed that unbalanced cylindrical magnetrons produce dense plasmas and good off-axis uniformity.

## Outline

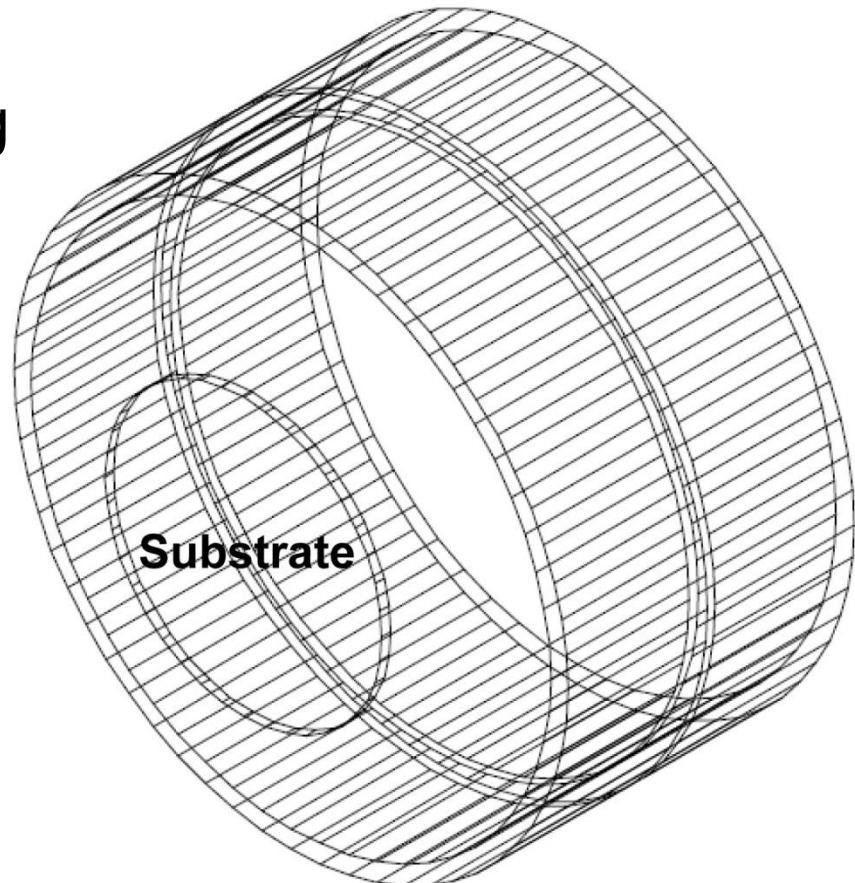
- System description
- Experimental methods
  - Plasma measurements
  - Thickness uniformity
  - Optical properties
- Results
- Conclusions

# Dual Unbalanced Cylindrical Magnetron

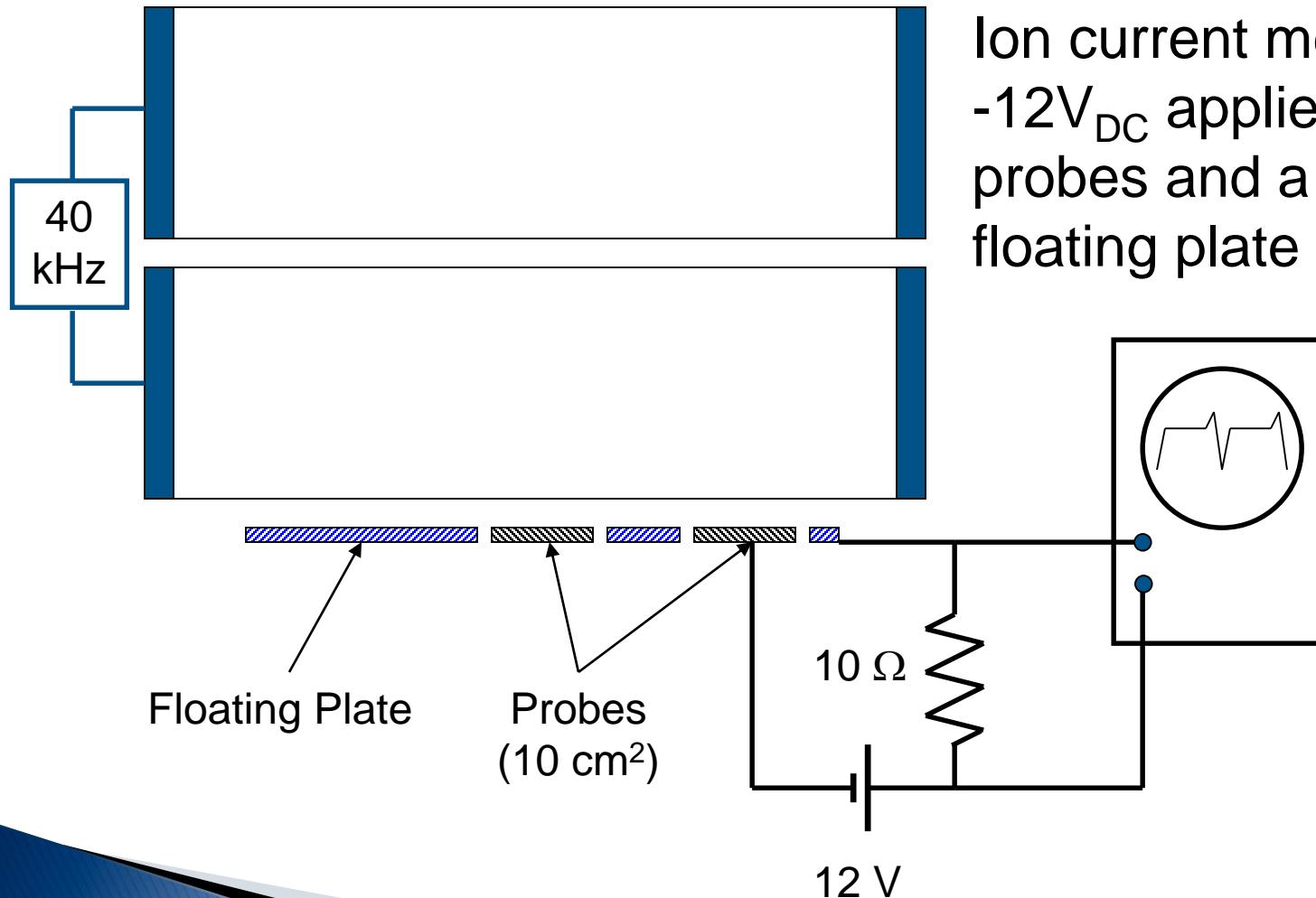


# System Description

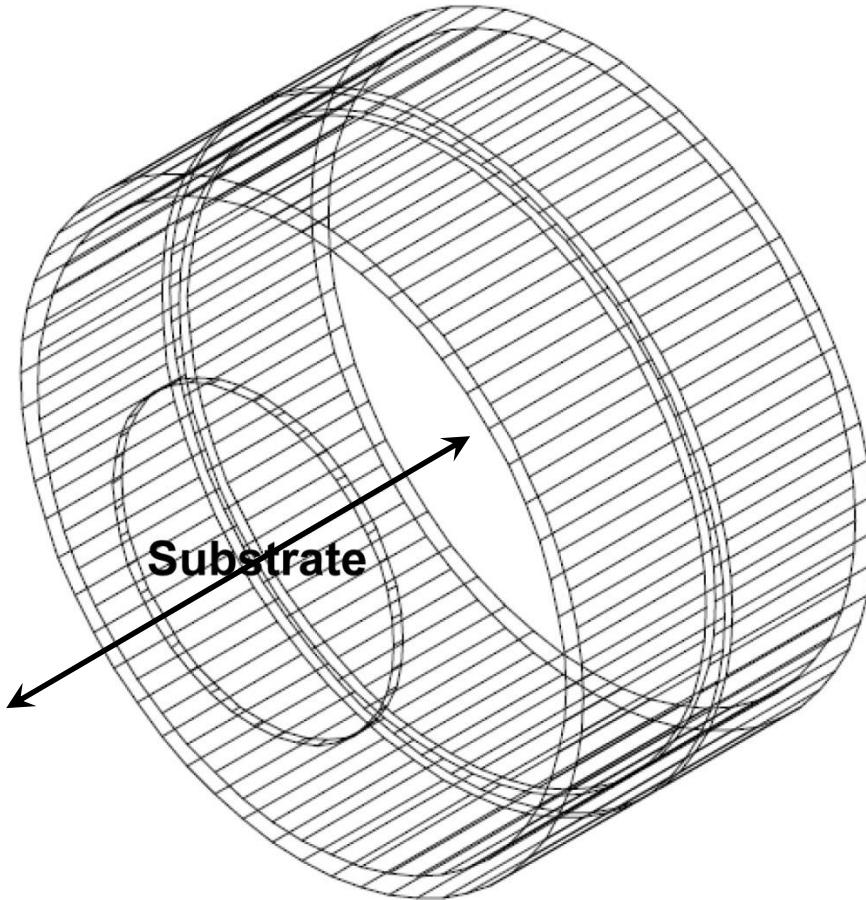
- Two 330 mm ID, 102 mm long targets for each material
- 40 kHz power
- Substrates placed off axis
- $Ta_2O_5$  and  $SiO_2$  sputtered in poisoned mode
- No substrate heat or motion



# Floating Potential and Ion Current Measurements



# Thickness Uniformity vs. Source to Substrate Distance



- 200 mm diameter Si substrates
- Distance from substrate to end of cathode varied
- $\text{Ta}_2\text{O}_5$  deposited at 4.0 kW and several pressures
- Relative thickness across substrate measured using spectral reflectance
- Optimum position chosen for optical coatings

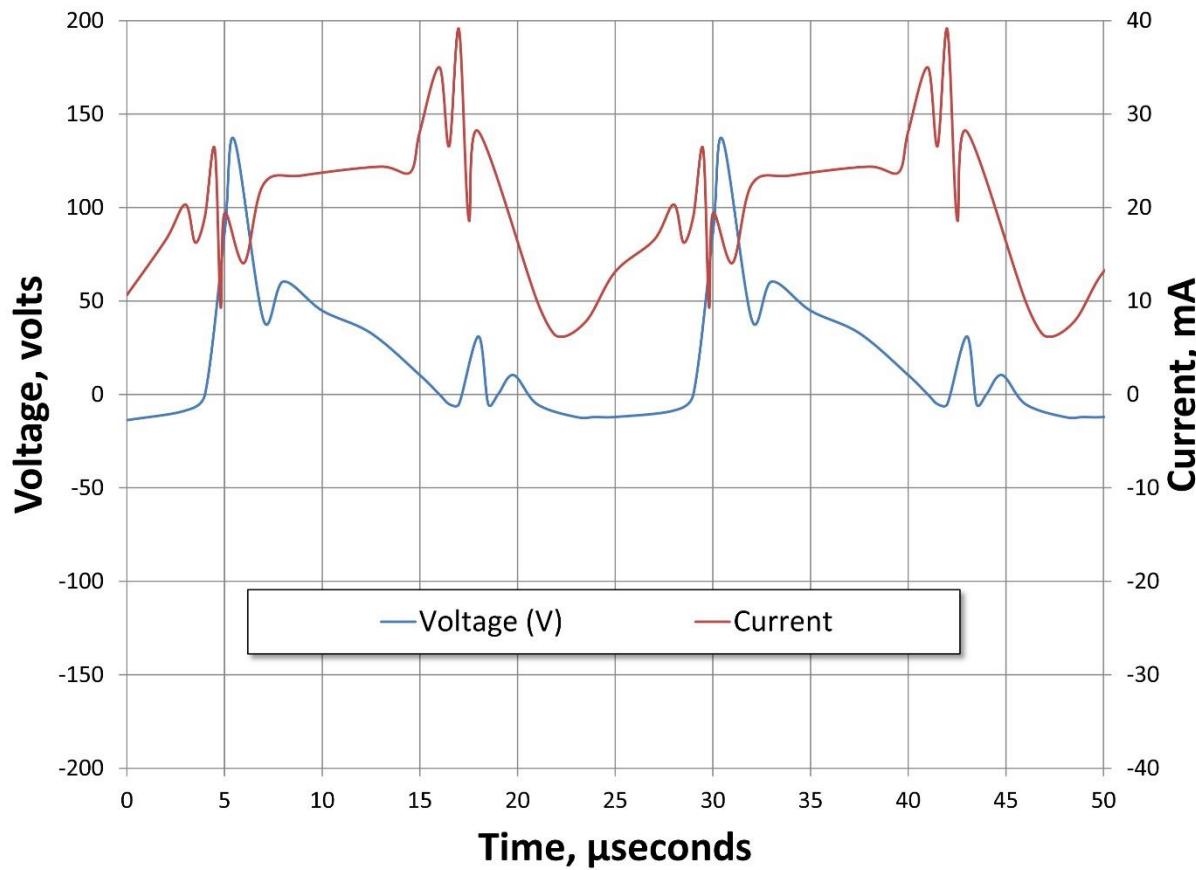
# Coating Conditions and Optical Measurements

	Power (kW)	Pressure (mT)	Ar Flow (sccm)	O <sub>2</sub> Flow (sccm)	Rate (nm/min)
Ta <sub>2</sub> O <sub>5</sub>	4.0	1.2	25	25	12
SiO <sub>2</sub>	2.0	2.1	35	50	13

- Two independent sets of ellipsometry measurements
  - n and k as functions of wavelength for Ta<sub>2</sub>O<sub>5</sub> at radial positions of 0, 50 and 100 mm
  - n<sub>633</sub> and thickness for Ta<sub>2</sub>O<sub>5</sub> and SiO<sub>2</sub> at radial positions of 0, 50 and 100 mm
  - n<sub>633</sub> and thickness for Ta<sub>2</sub>O<sub>5</sub> and SiO<sub>2</sub> as functions of temperature

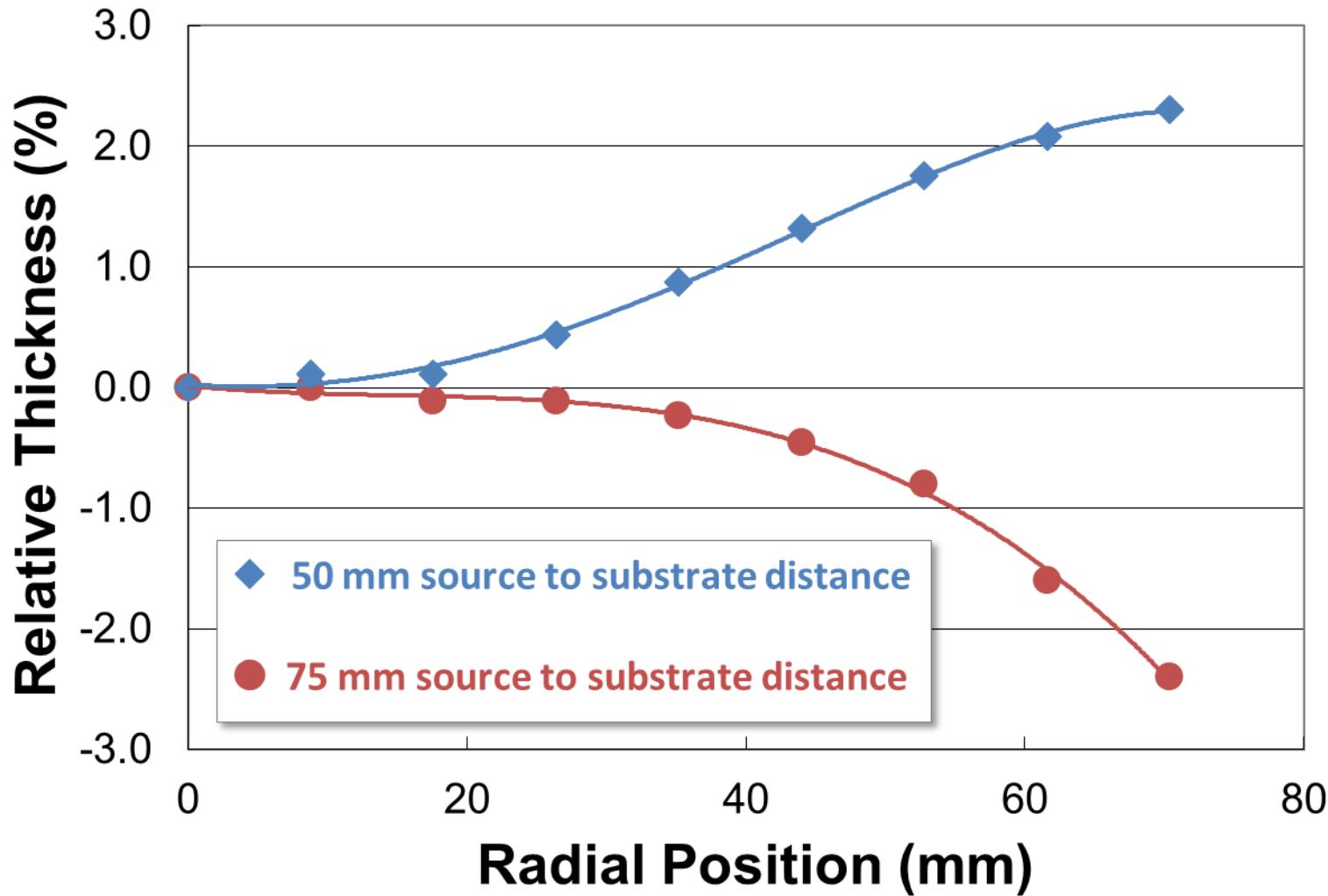
# Experimental Results

# Floating Potential and Ion Current

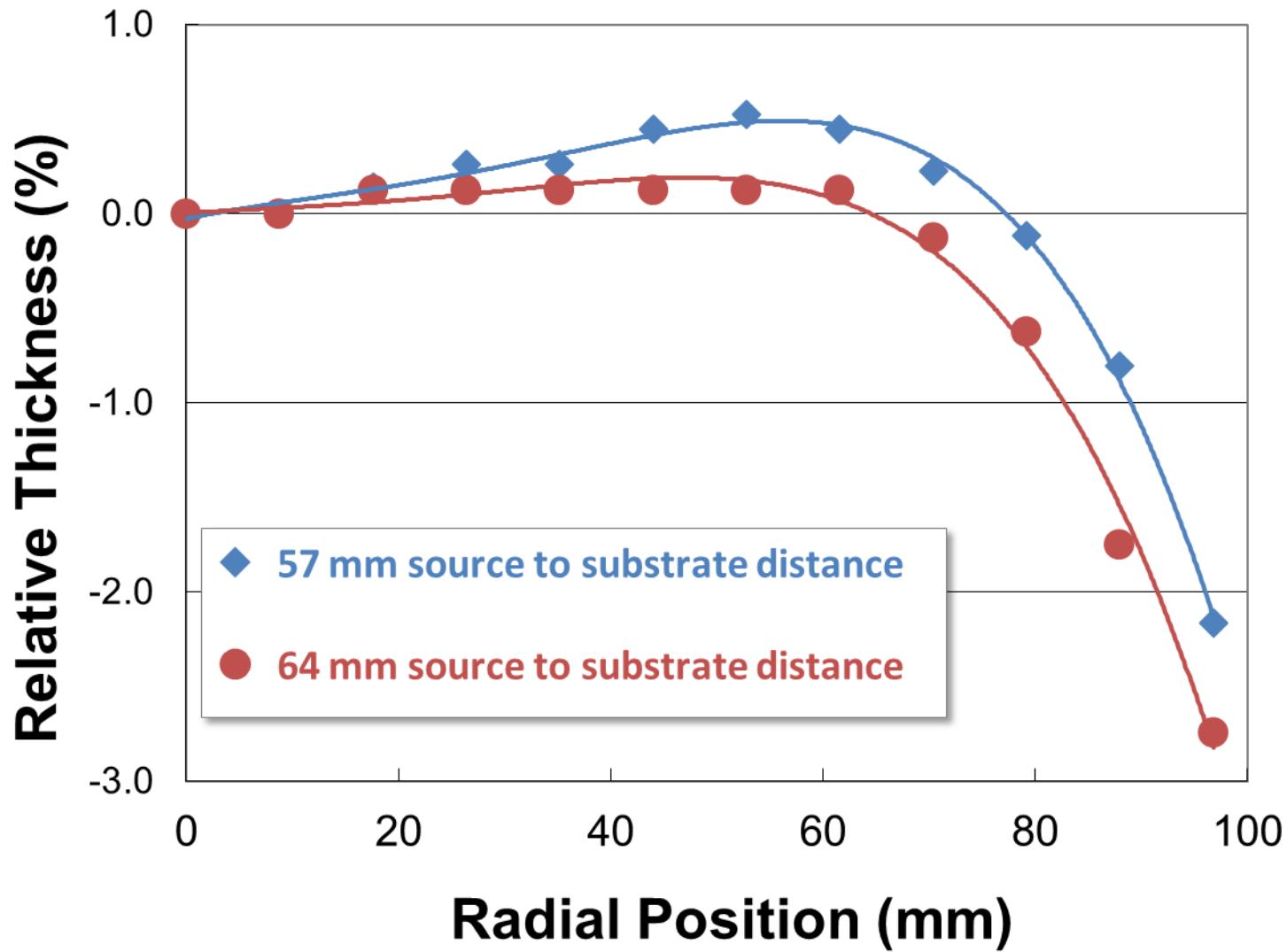


- Floating potential peaks when adjacent target becomes anode
- Ion flux equals  $1.2 \times 10^{16} / \text{cm}^2 \text{s}$  at center, about half that at edge
- Flux comparable to other ion enhanced processes

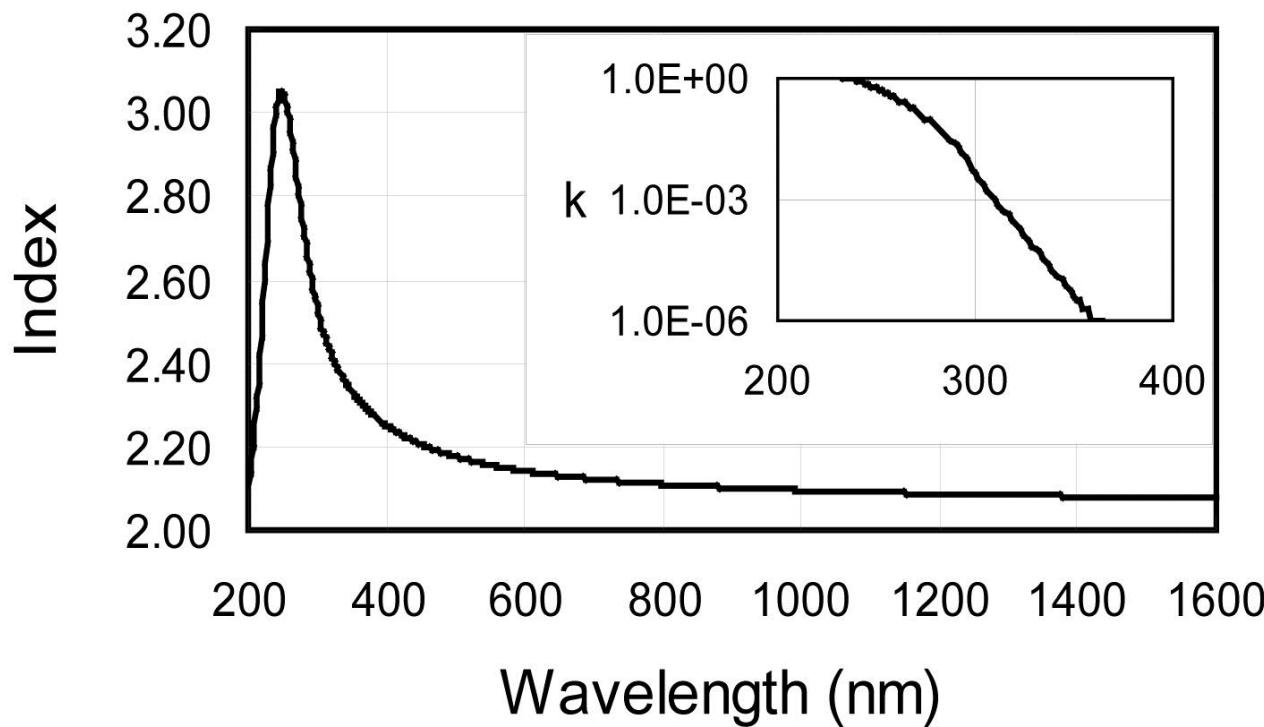
# Thickness Uniformity



# Thickness Uniformity

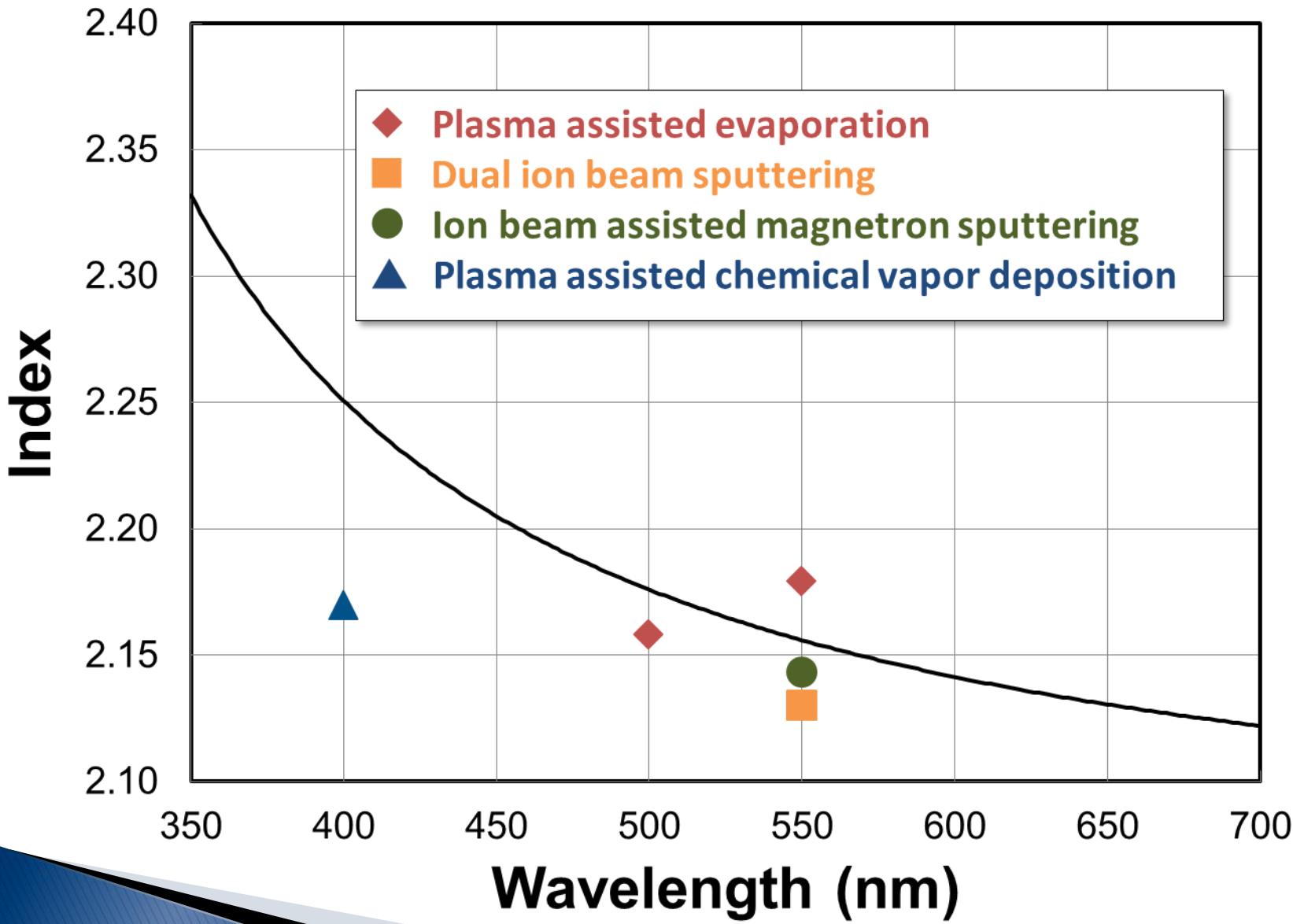


# Real and Imaginary Indices for $\text{Ta}_2\text{O}_5$

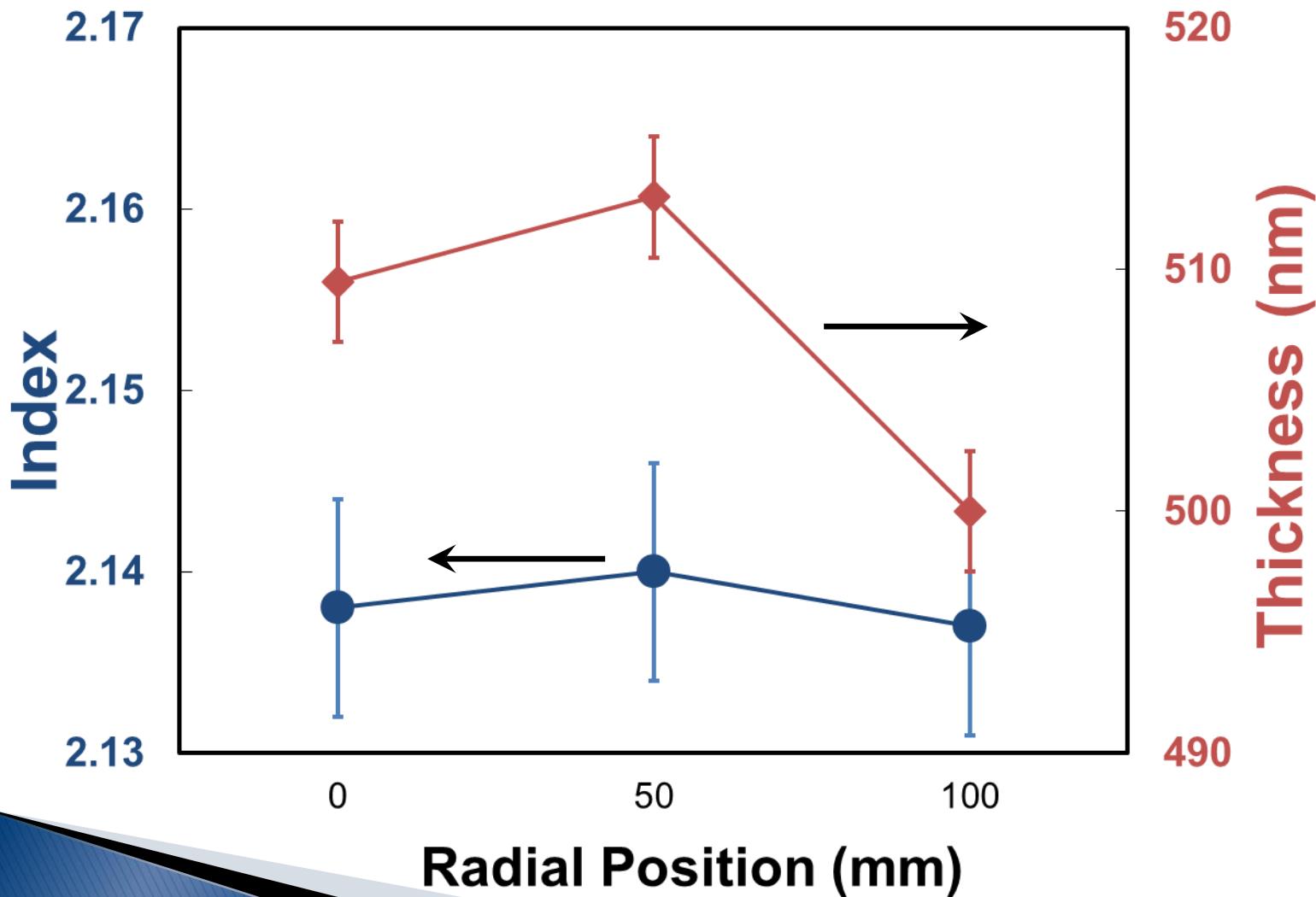


- Three radial positions indistinguishable on this scale
- For  $\lambda > 360$  nm,  $k < 1 \times 10^{-6}$

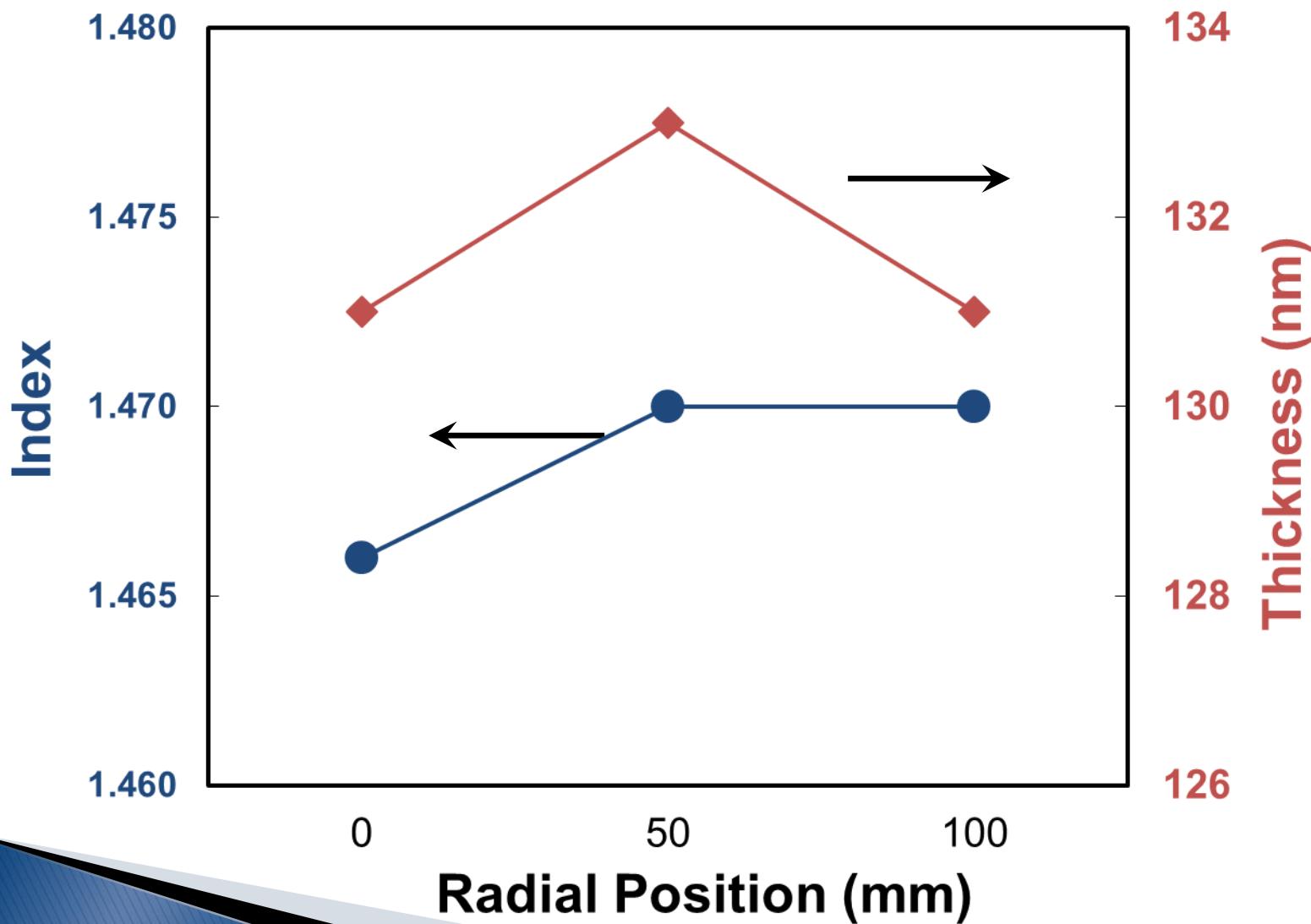
# Comparison of $\text{Ta}_2\text{O}_5$ Indices



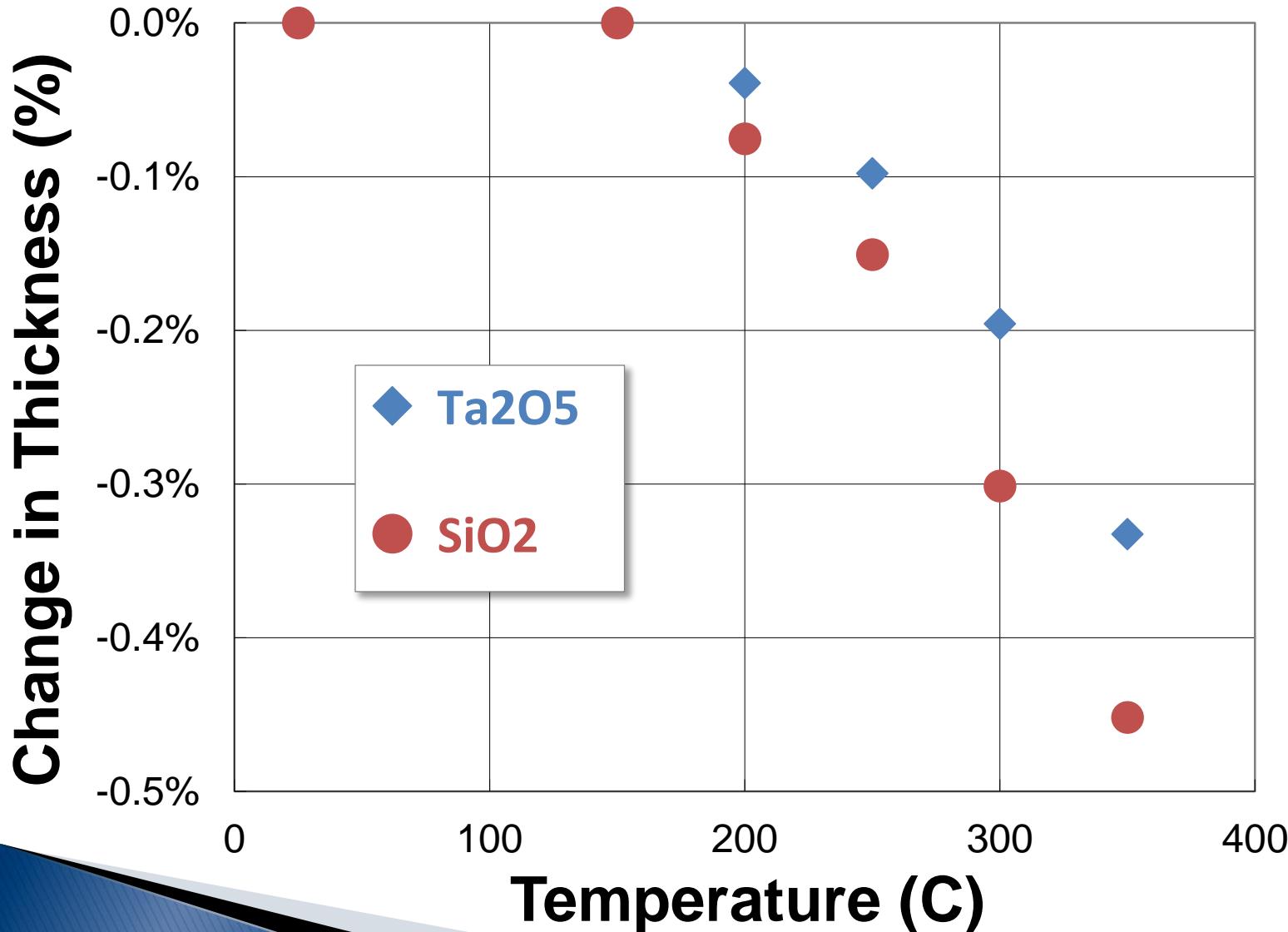
# Index (633 nm) and Thickness of $Ta_2O_5$ vs. Radial Position



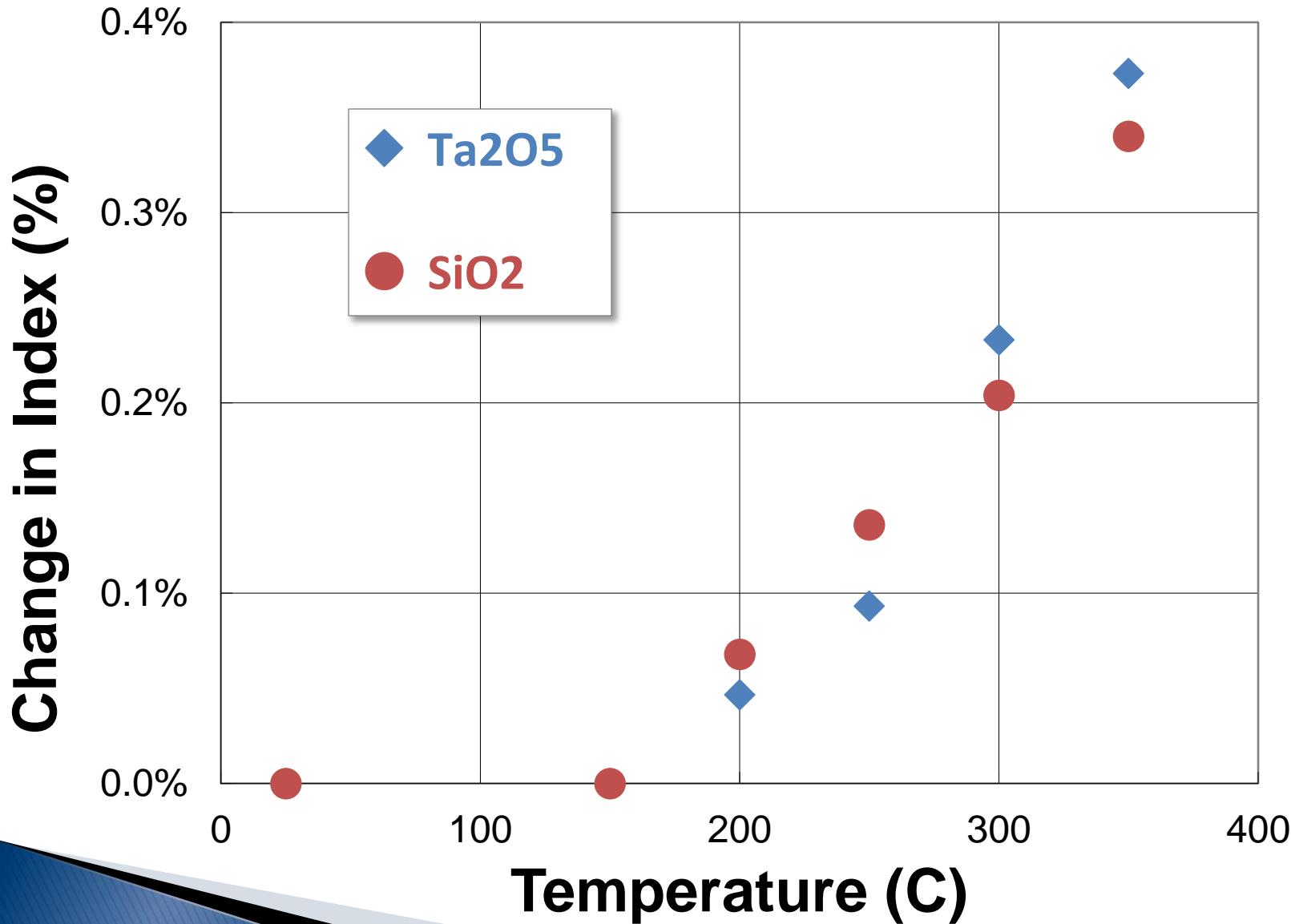
# Index (633 nm) and Thickness of $\text{SiO}_2$ vs. Radial Position



# Change in Thickness vs. Temperature



# Change in Index vs. Temperature



# Conclusions

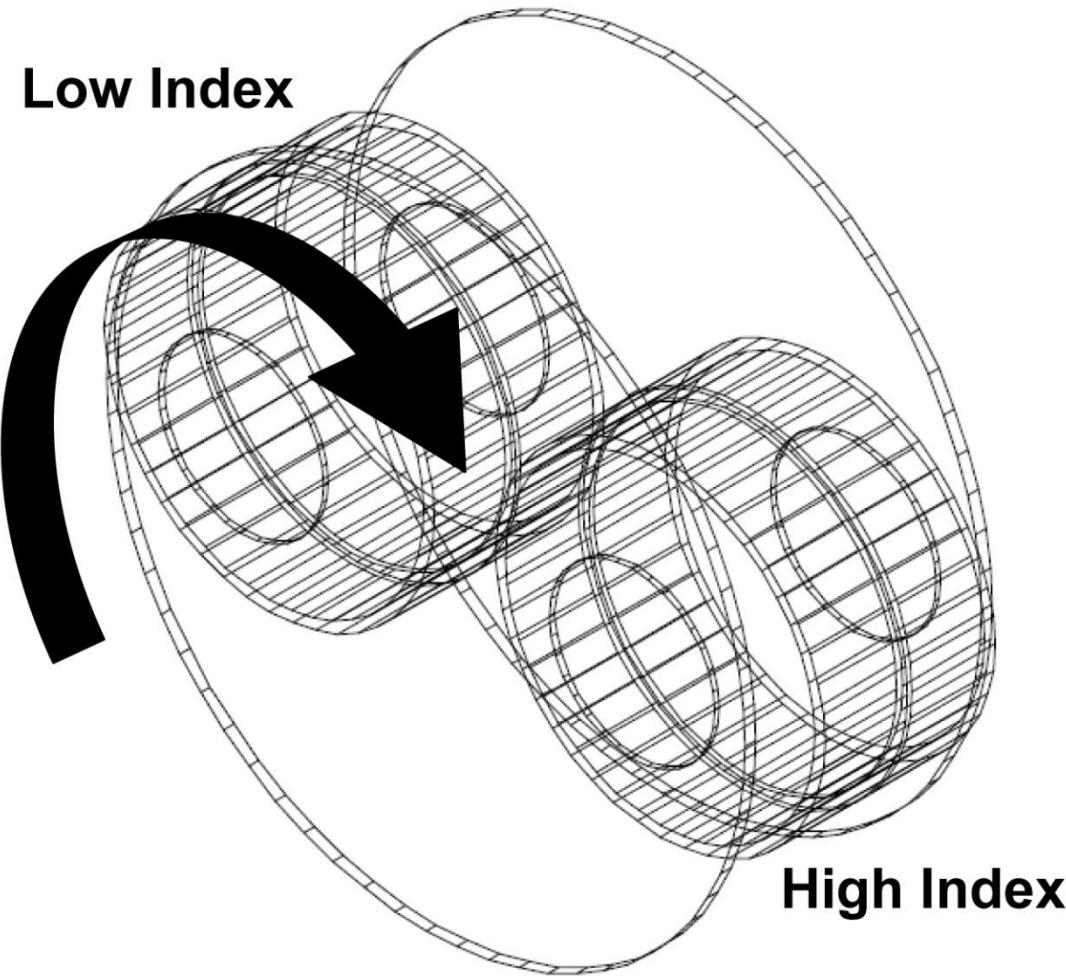
# Conclusions

- Off-axis sputtering with unbalanced cylindrical magnetrons produces coatings with excellent thickness uniformity and optical properties:
  - Significant low energy ion bombardment
  - Thickness uniformity  $\pm 0.25\%$  over  $\phi 160$  mm and  $\pm 1.3\%$  over  $\phi 200$  mm on stationary substrates
  - Excellent temperature stability with changes comparable to those seen in other ion enhanced coatings –  $\Delta n_d < 0.1\%$  over 350 C

# Conclusions, continued

- Level of ion bombardment adjustable through magnetic field imbalance
- Configuration reduces damage from energetic  $O^-$  and  $O_2^-$ , important for sensitive materials like OLEDs
- Design lends itself to very simple, high throughput coaters

# Coater Design



- High and low index materials deposit on multiple substrates simultaneously
- No substrate rotation, only indexing
- Extremely simple, robust source design
- No uniformity masks or shields